



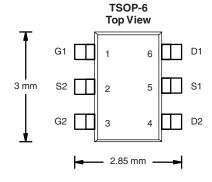
Dual N-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)		
20	0.125 at V _{GS} = 4.5 V	2.4		
20	0.200 at V _{GS} = 2.5 V	1.8		

FEATURES

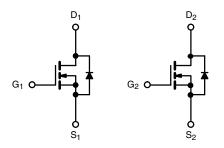
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- · Compliant to RoHS Directive 2002/95/EC





Ordering Information: Si3900DV-T1-E3 (Lead (Pb)-free)

Si3900DV-T1-GE3 (Lead (Pb)-free and Halogen-free)



N-Channel MOSFET

N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unle	ss otherwise r	noted		
Parameter		Symbol	5 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	20		V
Gate-Source Voltage		V _{GS}	± 12		V
Continuous Drain Current /T 150 °C\a	T _A = 25 °C	- I _D	2.4	2.0	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 85 °C		1.7	1.4	
Pulsed Drain Current (10 μs Pulse Width)		I _{DM}	8		Α
Continuous Source Current (Diode Conduction) ^a		I _S	1.05	0.75	
Mariana Barra Biraira di ad	T _A = 25 °C	P _D	1.15	0.83	w
Maximum Power Dissipation ^a	T _A = 85 °C] 'D	0.59	0.53	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Mariana la Antique	t ≤ 5 s	- R _{thJA}	93	110		
Maximum Junction-to-Ambient ^a	Steady State	' ¹thJA	130	150	°C/W	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	75	90		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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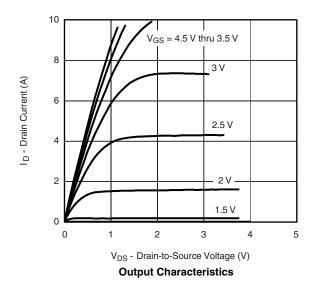
SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.6		1.5	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 12 V$			±100	nA	
Zoro Cata Valtago Drain Current	I _{DSS}	V _{DS} = 20 V, V _{GS} = 0 V			1		
Zero Gate Voltage Drain Current		$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 85 ^{\circ}\text{C}$			10	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	5			Α	
D : 0	В	V _{GS} = 4.5 V, I _D = 2.4 A		0.100	0.125	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 2.5 \text{ V}, I_D = 1.0 \text{ A}$		0.160	0.200	22	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 5 \text{ V}, I_{D} = 2.4 \text{ A}$		5		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 1.05 A, V _{GS} = 0 V		0.79	1.10	V	
Dynamic ^b							
Total Gate Charge	Q_g			2.1	4.0		
Gate-Source Charge	Q _{gs}	Q_{gs} $V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 2.4 \text{ A}$		0.3		nC	
Gate-Drain Charge	Q _{gd}			0.4		1	
Turn-On Delay Time	t _{d(on)}			10	17		
Rise Time	t _r	V_{DD} = 10 V, R_L = 10 Ω		30	50		
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 1 \text{ A}, V_{GEN} = 4.5 \text{ V}, R_g = 6 \Omega$		14	25	ns	
Fall Time	t _f			6	12	1	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 3.0 A, dI/dt = 100 A/μs		30	50		

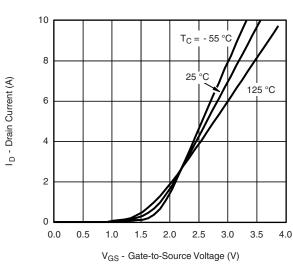
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



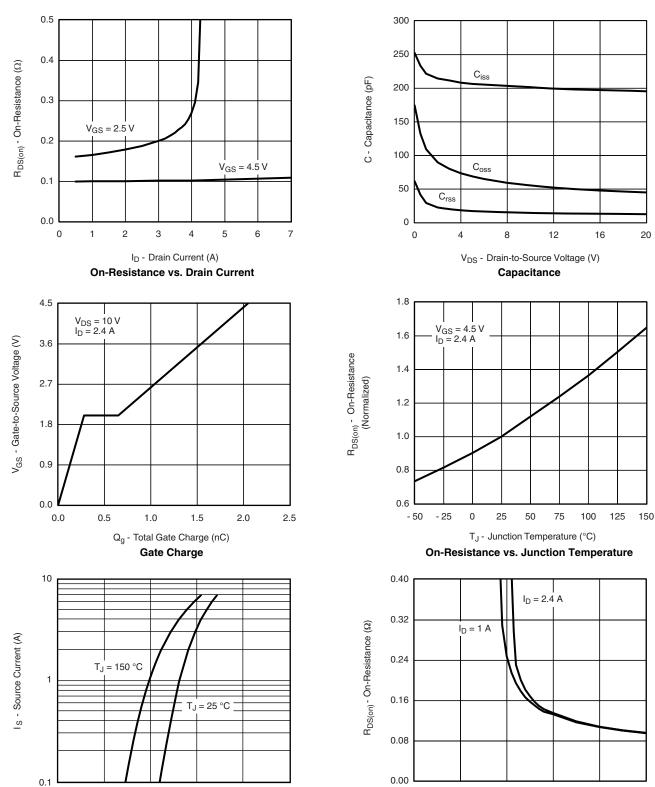








TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



0

0.3

0.6

0.9

 $\label{eq:VSD-Source-to-Drain Voltage} V_{SD} \text{ - Source-to-Drain Voltage (V)}$ Source-Drain Diode Forward Voltage

1.2

1.5

4

2

V_{GS} - Gate-to-Source Voltage (V)

On-Resistance vs. Gate-to-Source Voltage

0

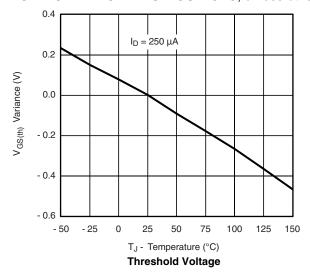
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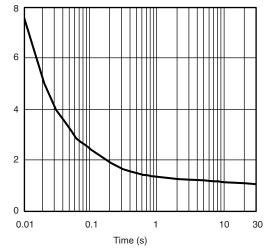
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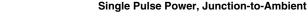
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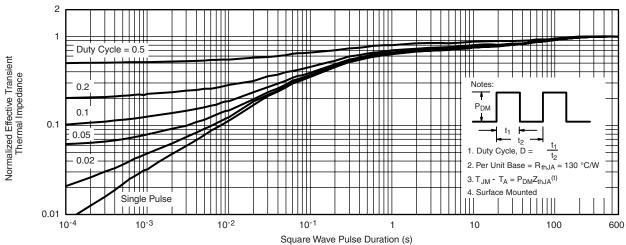
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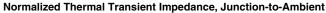
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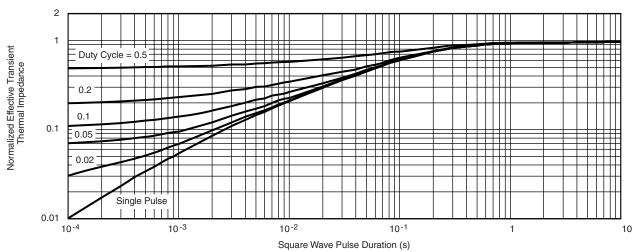








Power (W)



Normalized Thermal Transient Impedance, Junction-to-Foot

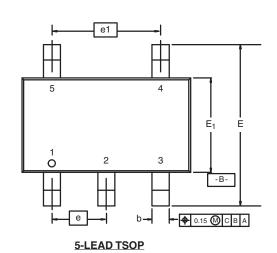
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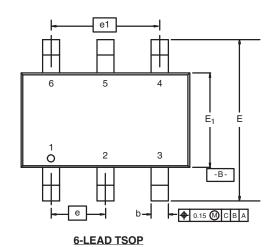


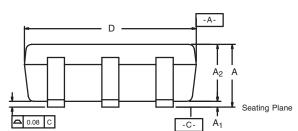


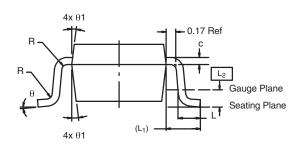
TSOP: 5/6-LEAD

JEDEC Part Number: MO-193C









	MILLIMETERS			INCHES				
Dim	Min	Nom	Max	Min	Nom	Max		
Α	0.91	-	1.10	0.036	-	0.043		
A ₁	0.01	-	0.10	0.0004	-	0.004		
A ₂	0.90	-	1.00	0.035	0.038	0.039		
b	0.30	0.32	0.45	0.012	0.013	0.018		
С	0.10	0.15	0.20	0.004 0.006		0.008		
D	2.95	3.05	3.10	0.116 0.120		0.122		
Е	2.70	2.85	2.98	0.106	0.112	0.117		
E ₁	1.55	1.65	1.70	0.061	0.065	0.067		
е		0.95 BSC			0.0374 BSC			
e ₁	1.80	1.90	2.00	0.071 0.075 0.0				
L	0.32	-	0.50	0.012	-	0.020		
L ₁	0.60 Ref			0.024 Ref				
L ₂	0.25 BSC			0.010 BSC				
R	0.10	-	-	0.004	-	-		
θ	0°	4°	8°	0°	4°	8°		
θ_1	7° Nom 7° Nom							
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540								

Document Number: 71200 18-Dec-06

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